

# UT54ACS240/UT54ACTS240

## Octal Buffers & Line Drivers, Inverted Three-State Outputs

Datasheet

November 2010

www.aeroflex.com/logic

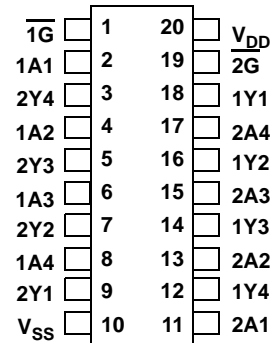


### FEATURES

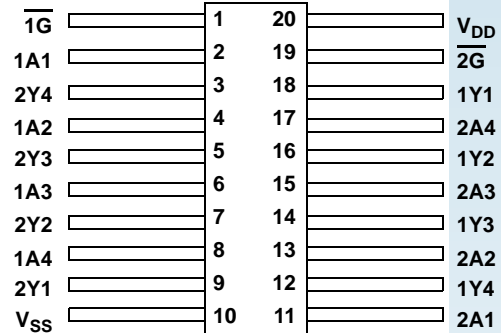
- ❑ Three-state outputs drive bus lines or buffer memory address registers
- ❑ 1.2μ CMOS
  - Latchup immune
- ❑ High speed
- ❑ Low power consumption
- ❑ Single 5 volt supply
- ❑ Available QML Q or V processes
- ❑ Flexible package
  - 20-pin DIP
  - 20-lead flatpack
- ❑ UT54ACS240 - SMD 5962-96568
- ❑ UT54ACTS240 - SMD 5962-96569

### PINOUTS

20-Pin DIP  
Top View



20-Lead Flatpack  
Top View



### DESCRIPTION

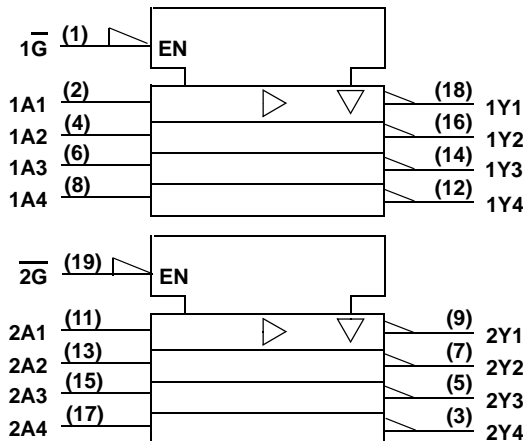
The UT54ACS240 and the UT54ACTS240 are inverting octal buffer and line drivers which improve the performance and density of three-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.

The devices are characterized over full military temperature range of -55°C to +125°C.

### FUNCTION TABLE

INPUTS		OUTPUT	
$\overline{1G}, \overline{2G}$	A	Y	
L	L	H	
L	H	L	
H	X	Z	

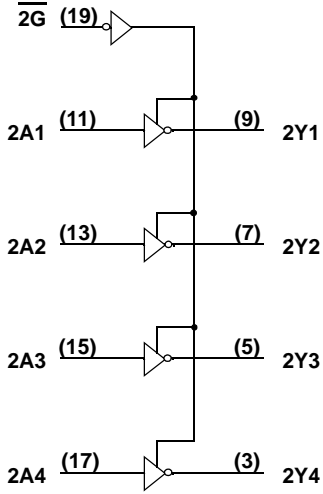
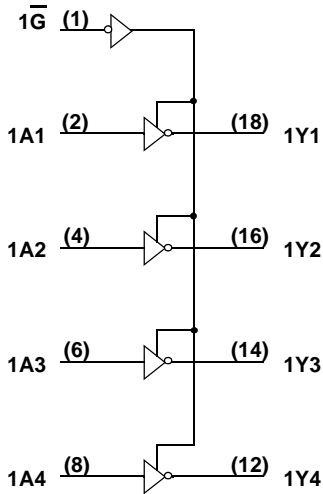
### LOGIC SYMBOL



**Note:**

1. Logic symbol in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

**LOGIC DIAGRAM**



## OPERATIONAL ENVIRONMENT<sup>1</sup>

PARAMETER	LIMIT	UNITS
Total Dose	1.0E6	rads(Si)
SEU Threshold <sup>2</sup>	80	MeV-cm <sup>2</sup> /mg
SEL Threshold	120	MeV-cm <sup>2</sup> /mg
Neutron Fluence	1.0E14	n/cm <sup>2</sup>

### Notes:

1. Logic will not latchup during radiation exposure within the limits defined in the table
2. Device storage elements are immune to SEU affects.

## ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	LIMIT	UNITS
V <sub>DD</sub>	Supply voltage	-0.3 to 7.0	V
V <sub>I/O</sub>	Voltage any pin	-.3 to V <sub>DD</sub> +.3	V
T <sub>STG</sub>	Storage Temperature range	-65 to +150	°C
T <sub>J</sub>	Maximum junction temperature	+175	°C
T <sub>LS</sub>	Lead temperature (soldering 5 seconds)	+300	°C
Θ <sub>JC</sub>	Thermal resistance junction to case	20	°C/W
I <sub>I</sub>	DC input current	±10	mA
P <sub>D</sub>	Maximum power dissipation	1	W

### Note:

1. Stresses outside the listed absolute maximum ratings may cause permanent damage to the device. This is a stress rating only, functional operation of the device at these or any other conditions beyond limits indicated in the operational sections is not recommended. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIMIT	UNITS
V <sub>DD</sub>	Supply voltage	4.5 to 5.5	V
V <sub>IN</sub>	Input voltage any pin	0 to V <sub>DD</sub>	V
T <sub>C</sub>	Temperature range	-55 to + 125	°C

## DC ELECTRICAL CHARACTERISTICS <sup>7</sup>

( $V_{DD} = 5.0V \pm 10\%$ ;  $V_{SS} = 0V$  <sup>6</sup>,  $-55^{\circ}C < T_C < +125^{\circ}C$ ); Unless otherwise noted,  $T_c$  is per the temperature range ordered.

SYMBOL	PARAMETER	CONDITION	MIN	MAX	UNIT
$V_{IL}$	Low-level input voltage <sup>1</sup> ACTS ACS			0.8 .3 $V_{DD}$	V
$V_{IH}$	High-level input voltage <sup>1</sup> ACTS ACS		.5 $V_{DD}$ .7 $V_{DD}$		V
$I_{IN}$	Input leakage current ACTS/ACS	$V_{IN} = V_{DD}$ or $V_{SS}$	-1	1	$\mu A$
$V_{OL}$	Low-level output voltage <sup>3</sup> ACTS ACS	$I_{OL} = 12.0mA$ $I_{OL} = 100\mu A$		0.40 0.25	V
$V_{OH}$	High-level output voltage <sup>3</sup> ACTS ACS	$I_{OH} = -12.0mA$ $I_{OH} = -100\mu A$	.7 $V_{DD}$ $V_{DD} - 0.25$		V
$I_{OZ}$	Three-state output leakage current	$V_O = V_{DD}$ and $V_{SS}$	-30	30	$\mu A$
$I_{OS}$	Short-circuit output current <sup>2,4</sup> ACTS/ACS	$V_O = V_{DD}$ and $V_{SS}$	-300	300	mA
$I_{OL}$	Output current <sup>10</sup> (Sink)	$V_{IN} = V_{DD}$ or $V_{SS}$ $V_{OL} = 0.4V$	12		mA
$I_{OH}$	Output current <sup>10</sup> (Source)	$V_{IN} = V_{DD}$ or $V_{SS}$ $V_{OH} = V_{DD} - 0.4V$	-12		mA
$P_{total}$	Power dissipation <sup>2, 8, 9</sup>	$C_L = 50pF$		2.1	mW/ MHz
$I_{DDQ}$	Quiescent Supply Current	$V_{DD} = 5.5V$		10	$\mu A$
$\Delta I_{DDQ}$	Quiescent Supply Current Delta ACTS	For input under test $V_{IN} = V_{DD} - 2.1V$ For all other inputs $V_{IN} = V_{DD}$ or $V_{SS}$ $V_{DD} = 5.5V$		1.6	mA
$C_{IN}$	Input capacitance <sup>5</sup>	$f = 1MHz @ 0V$		15	pF
$C_{OUT}$	Output capacitance <sup>5</sup>	$f = 1MHz @ 0V$		15	pF

**Notes:**

1. Functional tests are conducted in accordance with MIL-STD-883 with the following input test conditions:  $V_{IH} = V_{IH(min)} + 20\%$ ,  $- 0\%$ ;  $V_{IL} = V_{IL(max)} + 0\%$ ,  $- 50\%$ , as specified herein, for TTL, CMOS, or Schmitt compatible inputs. Devices may be tested using any input voltage within the above specified range, but are guaranteed to  $V_{IH(min)}$  and  $V_{IL(max)}$ .
2. Supplied as a design limit but not guaranteed or tested.
3. Per MIL-PRF-38535, for current density  $\leq 5.0E5$  amps/cm<sup>2</sup>, the maximum product of load capacitance (per output buffer) times frequency should not exceed 3,765 pF/MHz.
4. Not more than one output may be shorted at a time for maximum duration of one second.
5. Capacitance measured for initial qualification and when design changes may affect the value. Capacitance is measured between the designated terminal and  $V_{SS}$  at frequency of 1MHz and a signal amplitude of 50mV rms maximum.
6. Maximum allowable relative shift equals 50mV.
7. All specifications valid for radiation dose  $\leq 1E6$  rads(Si).
8. Power does not include power contribution of any TTL output sink current.
9. Power dissipation specified per switching output.
10. This value is guaranteed based on characterization data, but not tested.

## AC ELECTRICAL CHARACTERISTICS <sup>2</sup>

( $V_{DD} = 5.0V \pm 10\%$ ;  $V_{SS} = 0V$  <sup>6</sup>,  $-55^{\circ}C < T_C < +125^{\circ}C$ ); Unless otherwise noted,  $T_c$  is per the temperature range ordered.

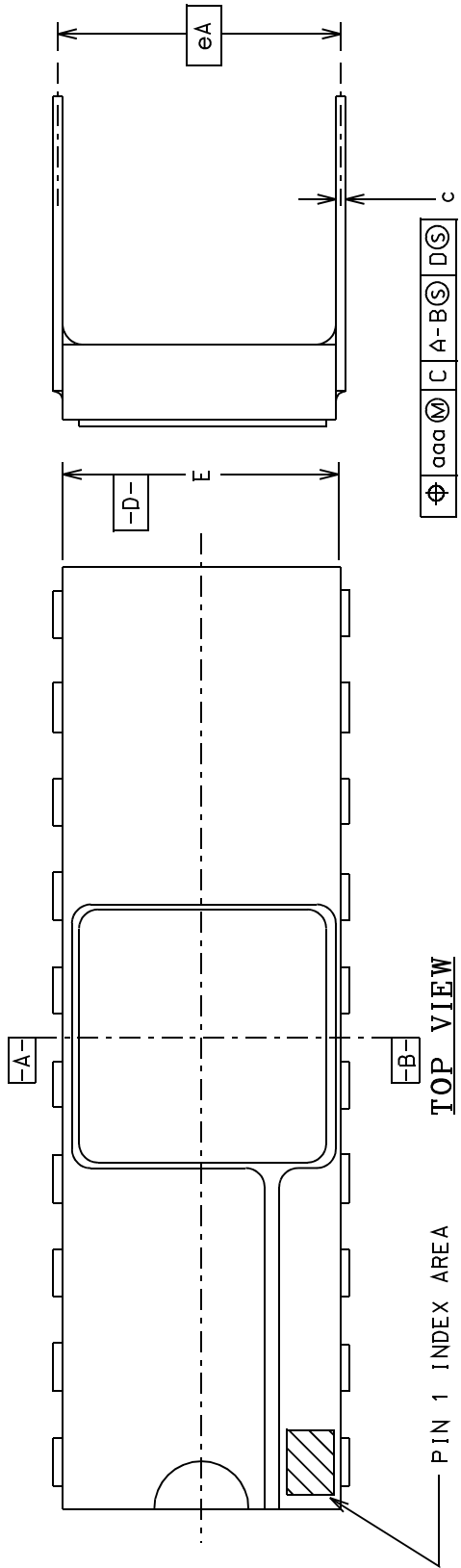
SYMBOL	PARAMETER	MINIMUM	MAXIMUM	UNIT
$t_{PLH}$	Input to $Y_n$	1	10	ns
$t_{PHL}$	Input to $Y_n$	1	13	ns
$t_{PZL}$	$\overline{G}$ low to $Y_n$ active	1	11	ns
$t_{PZH}$	$\overline{G}$ low to $Y_n$ active	2	13	ns
$t_{PLZ}$	$\overline{G}$ high to $Y_n$ three-state	2	11	ns
$t_{PHZ}$	$\overline{G}$ high to $Y_n$ three-state	2	14	ns

### Notes:

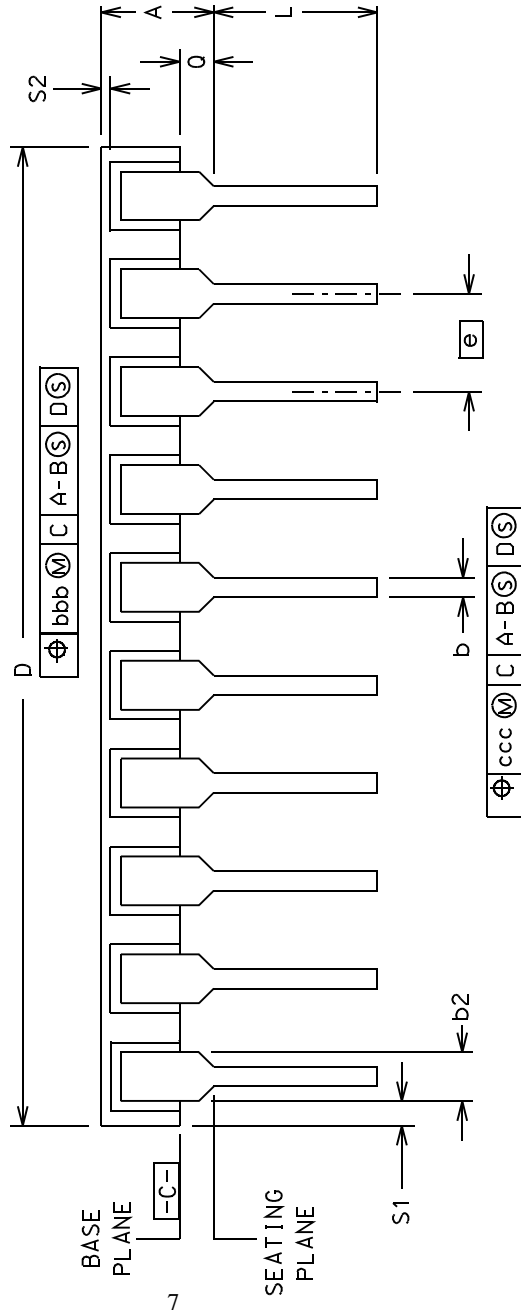
1. Maximum allowable relative shift equals 50mV.
2. All specifications valid for radiation dose  $\leq 1E6$  rads(Si).

# PACKAGING

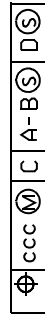
## Side-Brazed Packages



**SIDE VIEW**

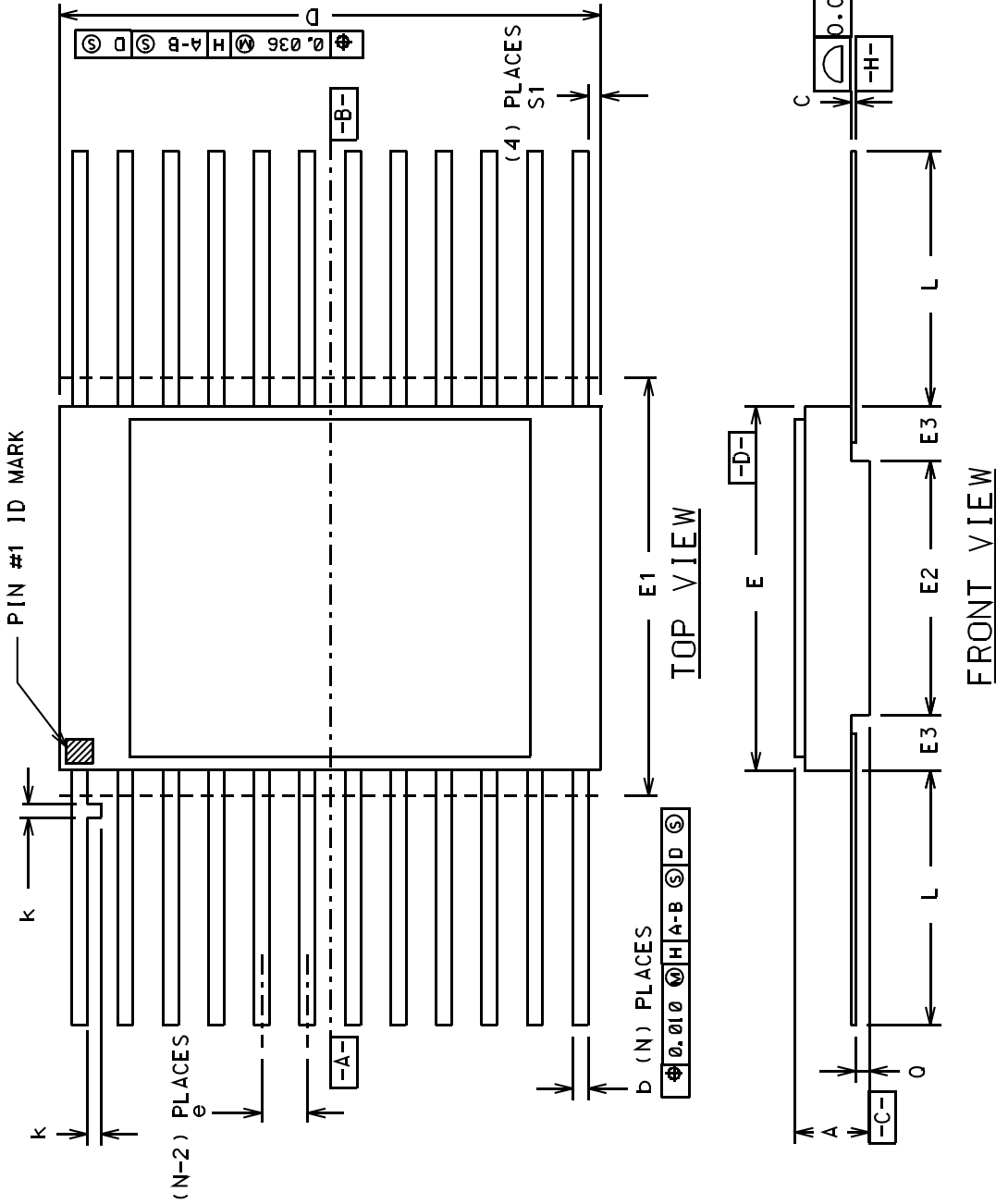


**FRONT VIEW**



PKG CONFIG	LEAD COUNT	MIL-STD-1835 DWG CONF C	DIMENSION SYMBOLS														
			A	b	b2	c	D	E	e	eA	L	Q	S1	S2	aaa	bbb	ccc
-01	14	D-1	0.200	0.026	0.065	0.018	0.785	0.310	0.100	0.300	0.200	0.060	---	---	0.015	0.030	0.010
-02	16	D-2	0.200	0.014	0.045	0.008	---	0.220	BSC	BSC	0.125	0.015	0.005	---	---	0.030	0.010
-03	20	D-8	0.200	0.026	0.065	0.018	0.840	0.310	0.100	0.300	0.200	0.060	---	---	0.015	0.030	0.010
			0.200	0.014	0.045	0.008	---	0.220	BSC	BSC	0.125	0.015	0.005	---	---	0.030	0.010
			0.200	0.026	0.065	0.018	1.060	0.310	0.100	0.300	0.200	0.070	---	---	0.015	0.030	0.010
			0.200	0.014	0.045	0.008	---	0.220	BSC	BSC	0.125	0.015	0.005	---	---	0.030	0.010

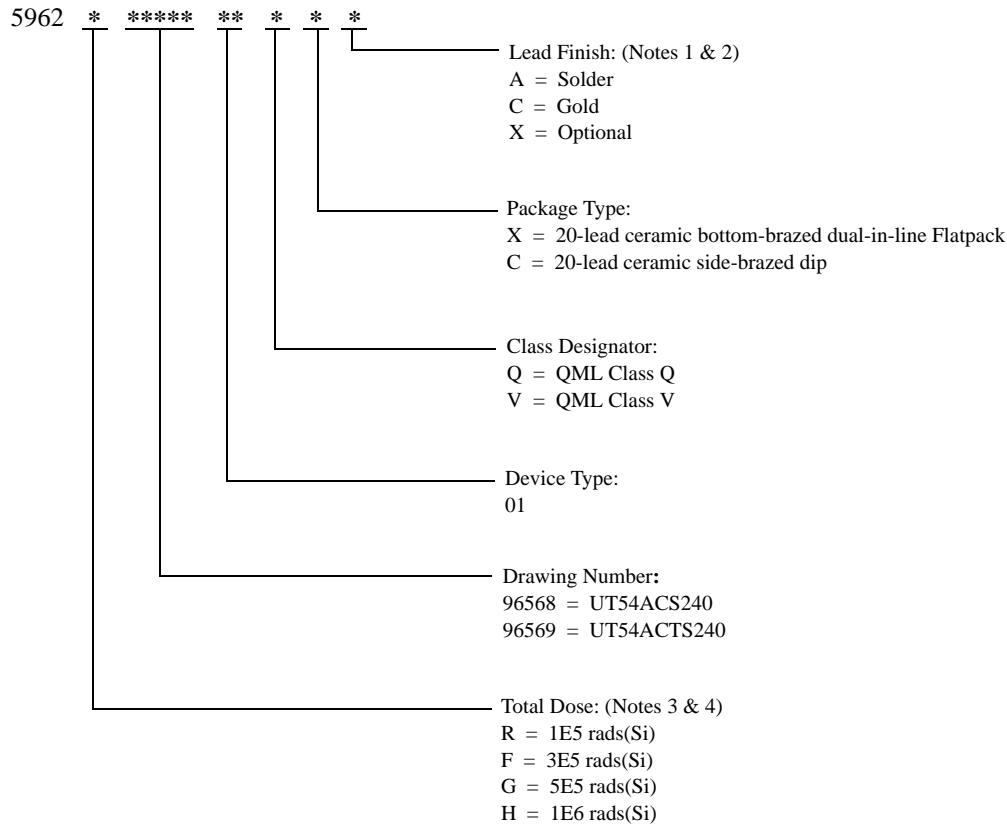
# FLATPACK PACKAGES



PKG CONFIG	LEAD COUNT	MIL-STD 1835 DWG CONF B	DIMENSION SYMBOLS												
			A	b	c	D	E	E1	E2	E3	e	k	L	0	S1
-03	14	F-2A	0.115 0.045	0.022 0.015	0.009 0.004	0.390 -----	0.260 0.235	0.290 -----	0.130 -----	0.030 -----	0.050 BSC	0.015 0.008	0.370 0.270	0.045 0.026	----- 0.005
-04	16	F-5A	0.115 0.045	0.022 0.015	0.009 0.004	0.440 -----	0.285 0.245	0.315 -----	0.130 -----	0.030 -----	0.050 BSC	0.015 0.008	0.370 0.250	0.045 0.026	----- 0.005
-05	20	F-9A	0.115 0.045	0.022 0.015	0.009 0.004	0.540 -----	0.300 0.245	0.330 -----	0.130 -----	0.030 -----	0.050 BSC	0.015 0.008	0.370 0.250	0.045 0.026	----- 0.000



**UT54ACS240/UT54ACTS240: SMD**



**Notes:**

1. Lead finish (A,C, or X) must be specified.
2. If an "X" is specified when ordering, part marking will match the lead finish and will be either "A" (solder) or "C" (gold).
3. Total dose radiation must be specified when ordering. QML Q and QML V not available without radiation hardening. For prototype inquiries, contact factory.
4. Device type 02 is only offered with a TID tolerance guarantee of 3E5 rads(Si) or 1E6 rads(Si) and is tested in accordance with MIL-STD-883 Test Method 1019 Condition A and section 3.11.2. Device type 03 is only offered with a TID tolerance guarantee of 1E5 rads(Si), 3E5 rads(Si), and 5E5 rads(Si), and is tested in accordance with MIL-STD-883 Test Method 1019 Condition A.

# *Aeroflex Colorado Springs - Datasheet Definition*

**Advanced Datasheet - Product In Development**

**Preliminary Datasheet - Shipping Prototype**

**Datasheet - Shipping QML & Reduced Hi-Rel**

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Our passion for performance is defined by three attributes represented by these three icons: solution-minded, performance-driven and customer-focused